



# PJW7N06A-AU

## 60V N-Channel Enhancement Mode MOSFET

**Voltage**

60 V

**Current**

6.6 A

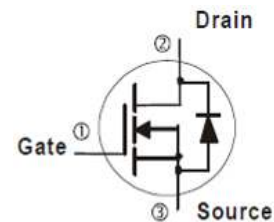
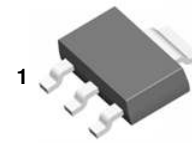
### Features

- $R_{DS(ON)}$ ,  $V_{GS}@10V$ ,  $I_D@6A < 34m\Omega$
- $R_{DS(ON)}$ ,  $V_{GS}@4.5V$ ,  $I_D@3A < 40m\Omega$
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc
- AEC-Q101 qualified
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

### Mechanical Data

- Case : SOT-223 Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight : 0.043 ounces, 0.123grams

SOT-223



### Maximum Ratings and Thermal Characteristics ( $T_A=25^\circ\text{C}$ unless otherwise noted)

PARAMETER	SYMBOL	LIMIT	UNITS
Drain-Source Voltage	$V_{DS}$	60	V
Gate-Source Voltage	$V_{GS}$	$\pm 20$	
Continuous Drain Current (Note 4)	$I_D$	$T_A=25^\circ\text{C}$	A
		$T_A=70^\circ\text{C}$	
Pulsed Drain Current (Note 1)	$I_{DM}$	26.4	
Power Dissipation	$P_D$	$T_A=25^\circ\text{C}$	W
		$T_A=70^\circ\text{C}$	
Operating Junction and Storage Temperature Range	$T_J, T_{STG}$	-55~175	$^\circ\text{C}$
Typical Thermal Resistance - Junction to Ambient (Note 4,5)	$R_{\theta JA}$	40.3	$^\circ\text{C/W}$

- Limited only By Maximum Junction Temperature



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## Electrical Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
<b>Static</b>						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V, I <sub>D</sub> =250uA	60	-	-	V
Gate Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =250uA	1	1.83	2.5	
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =6A	-	28	34	mΩ
		V <sub>GS</sub> =4.5V, I <sub>D</sub> =3A	-	33	40	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =60V, V <sub>GS</sub> =0V	-	-	1	uA
Gate-Source Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±20V, V <sub>DS</sub> =0V	-	-	±100	nA
<b>Dynamic</b> (Note 6)						
Total Gate Charge	Q <sub>g</sub>	V <sub>DS</sub> =30V, I <sub>D</sub> =6A, V <sub>GS</sub> =10V (Note 2,3)	-	20	-	nC
Gate-Source Charge	Q <sub>gs</sub>		-	3.8	-	
Gate-Drain Charge	Q <sub>gd</sub>		-	3.9	-	
Input Capacitance	C <sub>iss</sub>	V <sub>DS</sub> =25V, V <sub>GS</sub> =0V, f=1MHZ	-	1173	-	pF
Output Capacitance	C <sub>oss</sub>		-	63	-	
Reverse Transfer Capacitance	C <sub>rss</sub>		-	44	-	
Turn-On Delay Time	t <sub>d(on)</sub>	V <sub>DD</sub> =15V, I <sub>D</sub> =1A, V <sub>GS</sub> =10V, R <sub>G</sub> =6Ω (Note 2,3)	-	7.1	-	ns
Turn-On Rise Time	t <sub>r</sub>		-	25	-	
Turn-Off Delay Time	t <sub>d(off)</sub>		-	31	-	
Turn-Off Fall Time	t <sub>f</sub>		-	20	-	
<b>Drain-Source Diode</b>						
Maximum Continuous Drain-Source Diode Forward Current	I <sub>S</sub>	---	-	-	6.6	A
Diode Forward Voltage	V <sub>SD</sub>	I <sub>S</sub> =1A, V <sub>GS</sub> =0V	-	0.72	1.2	V

**NOTES :**

1. Pulse width ≤ 300us, Duty cycle ≤ 2%.
2. Essentially independent of operating temperature typical characteristics.
3. Repetitive rating, pulse width limited by junction temperature T<sub>J(MAX)</sub>=150°C. Ratings are based on low frequency and duty cycles to keep initial T<sub>J</sub> = 25°C.
4. The maximum current rating is package limited.
5. R<sub>θJA</sub> is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch<sup>2</sup> with 2oz.square pad of copper.
6. Guaranteed by design, not subject to production testing.



# PJW7N06A-AU

## TYPICAL CHARACTERISTIC CURVES

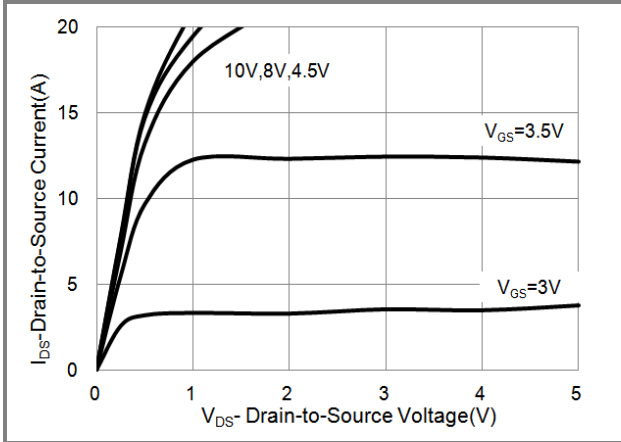


Fig.1 On-Region Characteristics

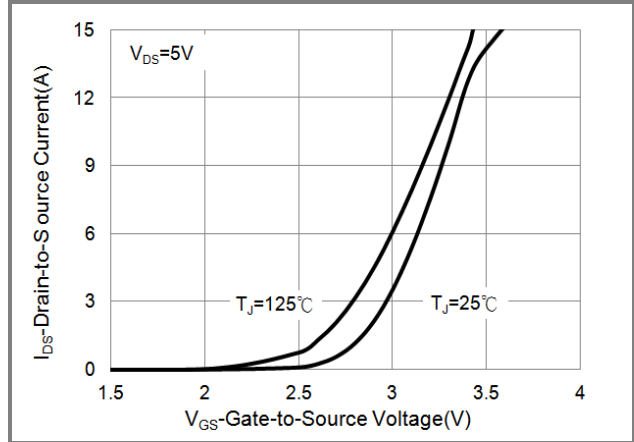


Fig.2 Transfer Characteristics

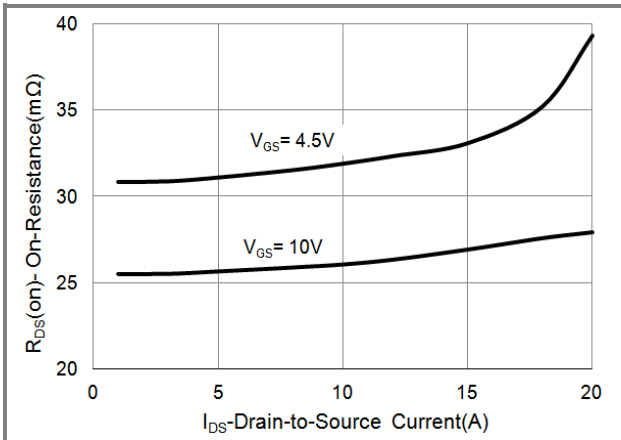


Fig.3 On-Resistance vs. Drain Current

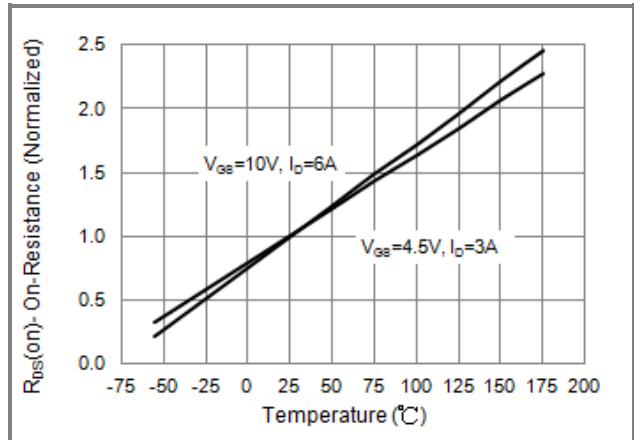


Fig.4 On-Resistance vs. Junction Temperature

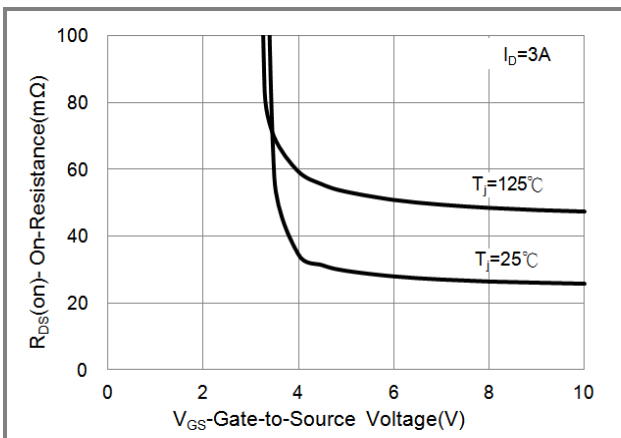


Fig.5 On-Resistance Variation with  $V_{GS}$

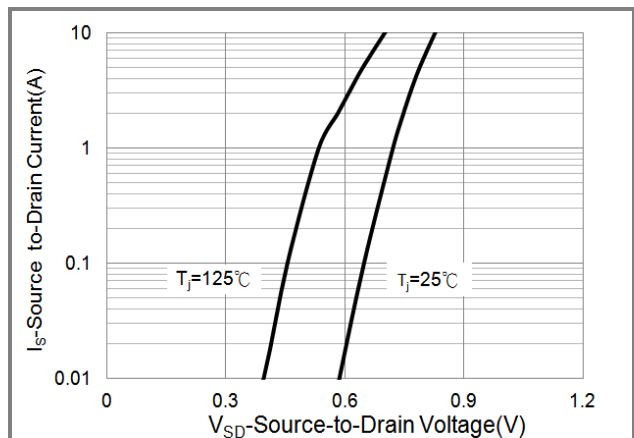


Fig.6 Body Diode Characteristics



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## TYPICAL CHARACTERISTIC CURVES

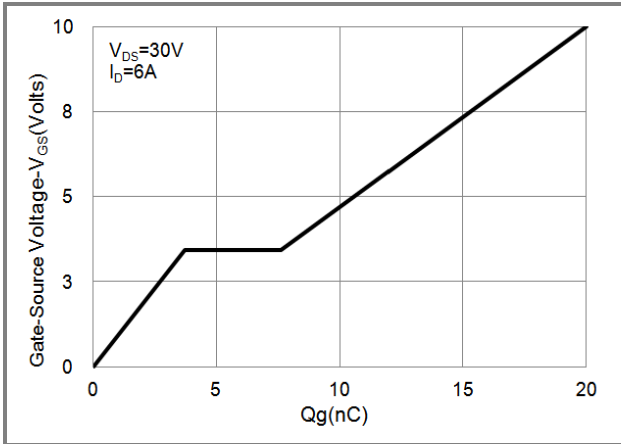


Fig.7 Gate-Charge Characteristics

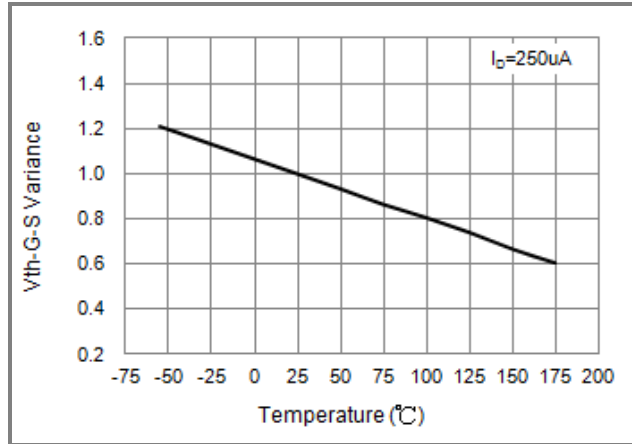


Fig.8 Threshold Voltage Variation with Temperature

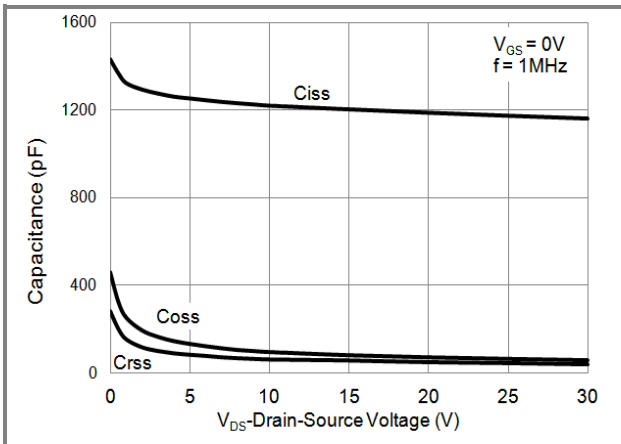


Fig.9 Capacitance vs. Drain-Source Voltage

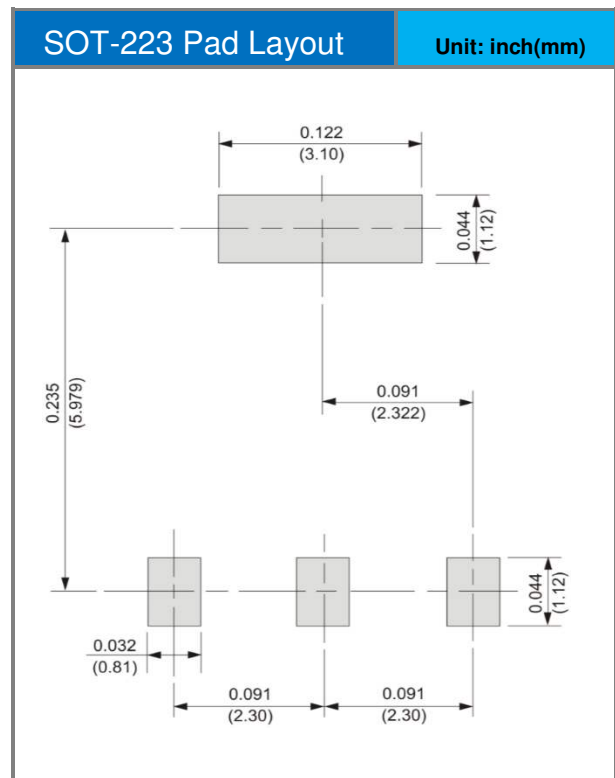
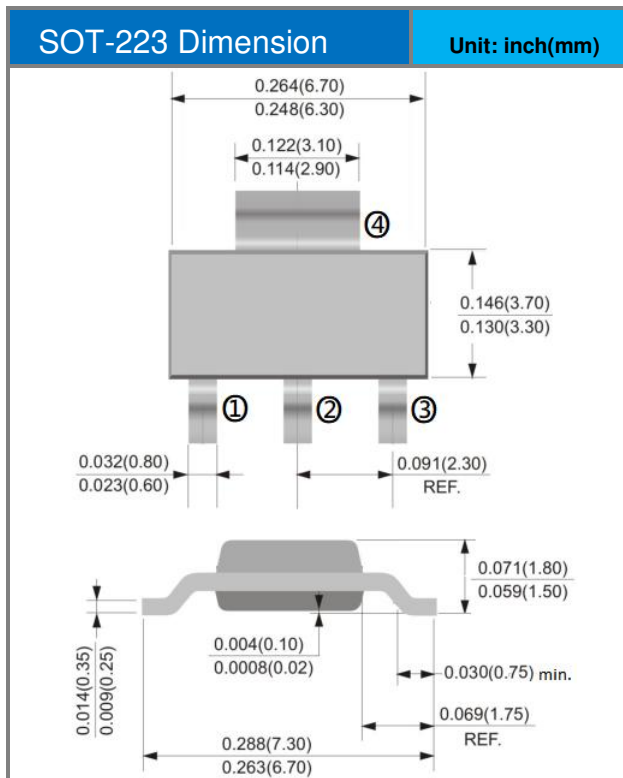


# PJW7N06A-AU

## Part No Packing Code Version

Part No Packing Code	Package Type	Packing Type	Marking	Version
PJW7N06A-AU_R2_000A1	SOT-223	2,500pcs / 13" reel	W7N06A	Halogen free

## Packaging Information & Mounting Pad Layout





## PJW7N06A-AU

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